### **GLF72525**



# Ultra-Low Current Consumption N-channel Load Switch with Low Input Voltage Range and Reverse Current Blocking

**Product Specification** 

#### **DESCRIPTION**

The GLF72525 Load Switch is a fully integrated 4 A NMOS load switch with I<sub>Q</sub>Smart<sup>TM</sup> advanced technology. The device is targeted for the mobile computing and data storage markets as a high performance solution for load switch applications.

The GLF72525 has a constant low on-resistance of 9.0 m $\Omega$  at the full input voltage range. The fixed rise time helps prevent undesirable inrush current when turned on and the internal EN pin pulldown resistor ensures the device remains in the shutdown mode when disabled. In shutdown mode the GLF72525 draws only 14 nA typical at 3.6 V input supply voltage.

The GLF72525 features a reverse current blocking protection. When the GLF72525 is disabled, it prevents reverse current flowing from the output to the input source.

The GLF72525 is available in a wafer level chip scale package (WLCSP) measuring 0.97 mm x 1.47 mm x 0.55 mm with a 0.5 mm pitch. This allows the user to save board space and increase cost savings.

#### **FEATURES**

Supply Voltage Range: 0.7 V to 3.6 V

• Low  $R_{ON}$ : 9.0  $m\Omega$  Typ

I<sub>OUT</sub> Max: 4 AUltra-Low I<sub>O</sub>:

5.6 μA Typ at 0.7 V<sub>IN</sub>

 $\circ~$  3.8  $\mu A$  Typ at 0.8  $V_{IN}$ 

 $\circ$  8.8  $\mu$ A Typ at 3.6  $V_{IN}$ 

• Ultra-Low I<sub>SD</sub>: 14 nA Typ @ 3.6 V<sub>IN</sub>

• Controlled V<sub>OUT</sub> Turn-on Time

 $\circ$  111  $\mu$ s at 0.7  $V_{IN}$ 

 $_{\odot}$   $\,$  113  $\mu s$  at 0.8  $V_{IN}$ 

87 μs at 3.6 V<sub>IN</sub>

• Internal EN Pull-Down Resistor

Integrated Output Discharge Switch

 Reverse Current Blocking Protection When Disabled

Operating Temperature Range: - 40 °C to 85 °C

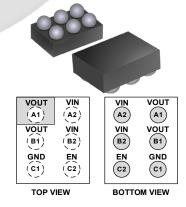
• HBM: 8 kV, CDM: 2 kV

• 0.97 mm x 1.47 mm x 0.55 mm, 6 Bumps Wafer Level Chip Scale Package

#### **APPLICATIONS**

- Data Storage, SSD
- Wearables
- Low Power Subsystems

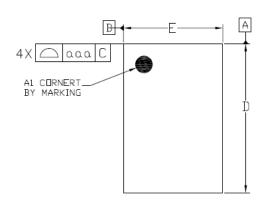
#### **PACKAGE**

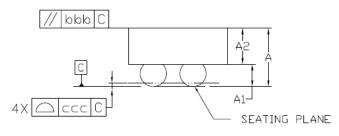


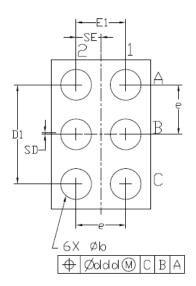
0.97 mm x 1.47 mm x 0.55 mm, 0.5 mm Pitch

## **Ultra-Low Current Consumption N-channel Load Switch** INTEGRATED POWER with Low Input Voltage Range and Reverse Current Blocking

#### **WLCSP PACKAGE OUTLINE**







Dimensional Ref.										
REF.	Min.	Nom.	Max.							
Α	0.500	0.550	0.600							
Α1	0.225	0.250	0.275							
A2	0.275	0.300	0.325							
D	1.460	1.470	1.485							
Ε	0.960	0.970	0.985							
D1	0.950	1.000	1.050							
E1	0.450	0.500	0.550							
Ь	0.260	0.310	0.360							
е	0.500 BSC									
SD	0.000 BSC									
SE	0.250 BSC									
Tol. of Form&Position										
999	0.10									
ььь	0.10									
333	0.05									
ddd	0.05									

#### Notes

- 1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.

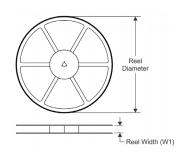


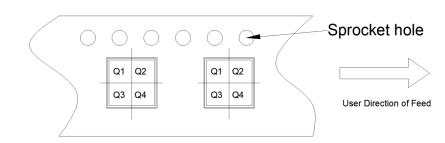
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#### TAPE AND REEL INFORMATION

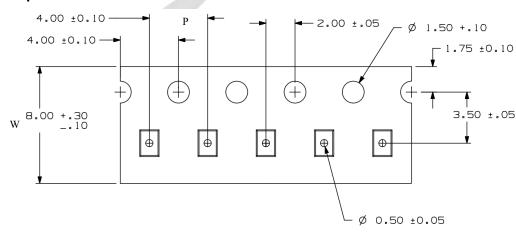
#### **Reel Dimensions**

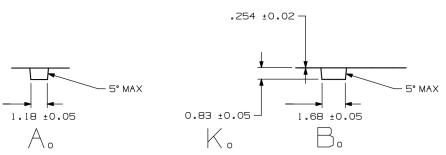
#### **Quadrant Assignments PIN1 Orientation Tape**





#### **Tape Dimensions**





Device	Package	PINs	SPQ	Reel Diameter (mm)	Reel Width W1	Α0	В0	K0	Р	w	PIN1
GLF72525	WLCSP	6	3000	180	9	1.18	1.68	0.83	4	8	Q1

- A0: Dimension designed to accommodate the component width B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers

## 单击下面可查看定价,库存,交付和生命周期等信息

## >>GLF(杰夫微)